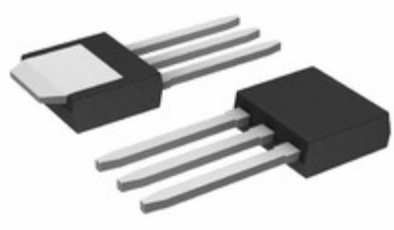










	GP2M004A065PG	
	Hersteller-Teilenummer:	GP2M004A065PG
	Hersteller / Marke:	Global Power Technologies Group
	Teil der Beschreibung:	MOSFET N-CH 650V 4A IPAK
	Datenblätter:	 GP2M004A065PG.pdf
	RoHs Status:	Bleifrei / RoHS-konform
<p>Image may be representation. See specs for product details.</p>	Lagerzustand:	New original, 7090 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS

Spezifikationen

Teilenummer	GP2M004A065PG
Hersteller	Global Power Technologies Group
Beschreibung	MOSFET N-CH 650V 4A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	7090 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	98.4W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	650V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4A (Tc)
Rds On (Max) @ Id, Vgs	2.4 Ohm @ 2A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	642pF @ 25V
Verpackung	Tube

GP2M004A065PG ist neu im Original, Suche GP2M004A065PG Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie GP2M004A065PG Global Power Technologies Group mit Garantie und Vertrauen. Anfrage GP2M004A065PG: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>GP2M004A065HG Global Power Technologies Group MOSFET N-CH 650V 4A TO220</p>	 <p>GP2M005A050PG Global Power Technologies Group MOSFET N-CH 500V 4.5A IPAK</p>	 <p>GP2M004A060PG Global Power Technologies Group MOSFET N-CH 600V 4A IPAK</p>	 <p>GP2M004A065CG Global Power Technologies Group MOSFET N-CH 650V 4A DPAK</p>
 <p>GP2M004A065FG Global Power Technologies Group MOSFET N-CH 650V 4A TO220F</p>	 <p>GP2M005A050CG Global Power Technologies Group MOSFET N-CH 500V 4.5A DPAK</p>	 <p>GP2M004A060HG Global Power Technologies Group MOSFET N-CH 600V 4A TO220</p>	 <p>GP2M005A060CG Global Power Technologies Group MOSFET N-CH 600V 4.2A DPAK</p>

heiße Teile

Mehr

 GP200E1M-G1	 GP200E1MTR-G1	 GP200EMTR-G1	 GP200MTR-G1	 GP2A231LRSA
 GP2A25J0000F	 GP2A25J0000F	 GP2A25NJ	 GP2A28A1J00F	 GP2A28N1J00F
 GP2AP002A00F	 GP2AP002S00F	 GP2AP003A10F	 GP2AP007A00F	 GP2AP008T00F
 GP2AP030A00F	 GP2AP052A00F	 GP2AP052A00F	 GP2L26K2	 GP2M002A060FG
 GP2M004A060PG	 GP2M004A065FG	 GP2M005A050PG	 GP2M005A060CG	 GP2M005A060FG
 GP2M005A060PGH	 GP2M008A060FGH	 GP2M010A060F	 GP2M010A065F	 GP2M011A090NG
 GP2M012A080NG	 GP2M020A050H	 GP2M020A060N	 GP2S24J0000F	 GP2S27T3
 GP2S27T3J00F	 GP2S27V6	 GP2S29SVJ00F	 GP2S40JJ000F	 GP2S700HCP
 GP2S700HCP	 GP2W0004YP	 GP2W0110YPS	 GP2W0112YPOF	 GP2W0118YPS
 GP2W0150YP0F	 GP2W3104XP0F	 GP2W3104YP0F	 GP2W3106YP0F	 GP2W3152YP0F

Contact us: Info@Y-IC.com

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